Doping of single-walled carbon nanotubes controlled via chemical transformation of encapsulated nickelocene

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Controlled doping of carbon nanotubes is elemental for their electronic applications. Here we report an approach to tune the polarity and degree of doping of single-walled carbon nanotubes via filling with nickelocene followed by encapsulated reactions. Using Raman, photoemission spectroscopy and transmission electron microscopy, we show that nickelocene molecules transform into nickel carbides, nickel and inner carbon nanotubes with reaction temperatures as low as 250 °C. The doping efficiency is determined for each chemical component. Synchronous charge transfer among the molecular components allows bipolar doping of the carbon nanotubes to be achieved in a broad range of ±0.0012 e− per carbon. 

1. Introduction

Single-walled carbon nanotubes (SWCNTs) possess unique physical, chemical and mechanical properties that are defined by their atomic structure. Since their discovery attempts were made to tailor the electronic properties towards applications in nanoelectronics such as logic elements, memory devices and electron field emitters. Over the last few years several methods have been established. These methods include chemisorption and physisorption of atoms and molecules on the nanotube outer surface, substitution of carbon with other elements, intercalation of carbon nanotube bundles and filling tubular interior channels. Among these methods, filling of carbon nanotubes is a very effective way to modify the electronic structure and the chemical environment in a controlled way. This is due to the fact that the SWCNT interiors can be filled with substances having different chemical and physical properties. It allows the SWCNT electronic properties to be modified via the encapsulation of donor or acceptor molecules. Because the encapsulated chemicals are much less affected by environmental factors, endohedral filling is a promising route towards the functionalisation of carbon nanotubes for electronic applications.

Organometallic and coordination compounds are promising functional fillers as reported in some of the early studies with metallocenes,23–25 metal phthalocyanine,26 and metal acetylacetonates. Only a few papers were dedicated to theoretical and experimental studies of the electronic properties of metallocene-filled SWCNTs. On the theoretical side, it has been shown that encapsulation of different metallocenes (C8H5)M, where M is a metal center, leads to electron doping of SWCNTs that depends on their chirality and the type of metal atom. On the experimental side, electron doping was observed for SWCNT encapsulating ferrocene and cerocene, where low doping levels were achieved.

Encapsulated inside SWCNTs, organometallic molecules can be reacted to form metallic particles that subsequently catalyse the formation of inner carbon nanotubes in a confined tubular environment. It was shown that such endohedral reactions can lead to changes in the electron doping of SWCNTs only to lower levels. The control of both electron and hole doping of SWCNTs at the highest possible levels using one precursor would make the endohedral process promising as a functionalisation route for carbon nanotubes. Furthermore, finding a molecular precursor that can be reacted at reduced temperatures is a prerequisite for the method to be adapted in a process line for device fabrication.

In the present work we synthesise nickelocene (NiCp2)-filled SWCNTs and study their physical properties in response to heating under vacuum. We demonstrate that SWCNTs can be filled with nickelocene with a large filling factor. Using Raman spectroscopy we show that at temperatures ranging from 250 °C to 1200 °C nickelocene molecules react with one another to grow inner tubes inside the outer SWCNTs at high yield. The chemical state of the encapsulated compounds has been analysed at every annealing step by X-ray photoelectron
spectroscopy (XPS). The formation of metallic clusters has been observed by transmission electron microscopy (TEM). The electronic structure of SWCNTs has been studied by XPS and ultraviolet photoelectron spectroscopy (UPS). By tracing the carbon $\pi$ peak energy in the valence band spectra, we show that different chemical states of the SWCNT interior allow both electron and hole doping of the SWCNTs at high doping levels, as illustrated in Fig. 1. Our results demonstrate that the chemical transformation of nickelocene can be utilized for the directional modification of the SWCNT electronic properties at reaction temperatures as low as 250 °C.

2. Experimental

Single-walled carbon nanotubes with a mean diameter of 1.7 nm\textsuperscript{18} were synthesised by the enhanced direct injection pyrolytic synthesis (e-DIPS) method. SWCNT buckypapers were pre-heated in air at 500 °C for one hour. Filling with nickelocene (NiC\textsubscript{2}, chemical formula C\textsubscript{10}H\textsubscript{10}Ni) was done by heating the buckypapers with NiC\textsubscript{2} powder inside a vacuum (better than $5 \times 10^{-6}$ mbar) sealed Pyrex-glass tube at 50 °C for five days. A conversion of nickelocene-filled SWCNTs to DWCNTs was carried out via annealing at temperatures in the range of 250–1200 °C for 2 hours in a vacuum chamber evacuated to a pressure better than $2 \times 10^{-6}$ mbar. Raman spectroscopy measurements were performed at room temperature using a Horiba Jobin Yvon LabRAM spectrometer equipped with a HeNe laser that operates at a wavelength of 633 nm ($E_{\text{ex}} = 1.96$ eV). The radial breathing mode (RBM) lines in the Raman spectra were fitted to Voigt peaks and the area intensities were calculated using PeakFit v4.12. TEM was performed with a JEOL JEM-2100F microscope equipped with Delta spherical aberration (Cs) correctors\textsuperscript{39} at an accelerating voltage of 60 kV. X-ray and ultraviolet photoemission spectra were recorded with monochromatic Al K\textsubscript{α} ($1486.6$ eV) and He II ($40.8$ eV) radiation, respectively, using a hemispherical SCIENTA RS4000 photoelectron energy analyzer. The experimental resolution and the Fermi energy were determined from the Fermi edge of clean Au substrates. The overall energy resolutions were better than 20 meV for ultraviolet and 450 meV for X-ray photoemission spectroscopy. All photoemission measurements were carried out at room temperature.

3. Results and discussion

3.1. Formation of double-walled carbon nanotubes

Raman spectroscopy is a non-destructive method well suited for observing the formation of carbon nanotubes. It has been proven to be a valuable tool to analyze the transformation of filled SWCNTs into DWCNTs. Examples are nanotubes containing molecules like fullerenes\textsuperscript{40} ferrocene\textsuperscript{25,41,42} cerocene\textsuperscript{36} and platinum acetylacetonate.\textsuperscript{37}

Fig. 2a shows the evolution of the RBM-band of SWCNTs’ Raman spectra acquired at a laser wavelength of 633 nm ($E_{\text{ex}} = 1.96$ eV) upon filling with nickelocene and subsequent annealing at temperatures between 400 °C and 1200 °C for 2 hours. The radial breathing mode (RBM) lines in the Raman spectra were fitted to Voigt peaks and the area intensities were calculated using PeakFit. TEM was performed with a JEOL JEM-2100F microscope equipped with Delta spherical aberration (Cs) correctors at an accelerating voltage of 60 kV. X-ray and ultraviolet photoemission spectra were recorded with monochromatic Al K\textsubscript{α} ($1486.6$ eV) and He II ($40.8$ eV) radiation, respectively, using a hemispherical SCIENTA RS4000 photoelectron energy analyzer. The experimental resolution and the Fermi energy were determined from the Fermi edge of clean Au substrates. The overall energy resolutions were better than 20 meV for ultraviolet and 450 meV for X-ray photoemission spectroscopy. All photoemission measurements were carried out at room temperature.

Fig. 2 (a) Raman spectra of the pristine, nickelocene-filled SWCNTs and samples annealed at temperatures between 400 °C and 1200 °C for 2 hours measured at a laser wavelength of 633 nm ($E_{\text{ex}} = 1.96$ eV), vertically offset by an arbitrary constant for clarity, a.u. refers to arbitrary units. (b) Total area intensity of the (12,3) and (13,1) RBM peaks normalized to the outer tube RBM peak area plotted against annealing temperature.
annealing at temperatures of 400–1200 °C. The RBM-band of the pristine SWCNTs is located at frequencies ranging from 125 to 160 cm$^{-1}$. After filling with nickelocene the RBM lines are upshifted by 4 cm$^{-1}$, as previously observed for SWCNTs filled with other molecules. After annealing they are shifted back to the original position and additional peaks appear at 212, 216 and 253 cm$^{-1}$. Taking into consideration that the position of RBM peaks is inversely proportional to the nanotube diameter, these new peaks are of inner tubes whose diameters are smaller than those of the outer tubes. Note that the inner tube peak being as high as the outer tube peak means that DWCNTs are produced in a high yield as a consequence of a high filling degree of the SWCNTs with nickelocene. Notably, the largest inner tube peak is composed of two lines, one at 212 cm$^{-1}$ assigned to the (12,3) nanotube with a diameter of 1.08 nm and the other at 216 cm$^{-1}$ assigned to the (13,1) tube with a diameter of 1.06 nm. The peak located at 253 cm$^{-1}$ is of the (11,1) tube with a diameter of 0.91 nm. Given a mean diameter of the pristine SWCNTs (1.7 nm) and a van der Waals distance (0.335 nm) between the outer and inner graphene layers of DWCNTs, we estimated an inner tube mean diameter of $\sim 1.03$ nm. The (12,3) and (13,1) tubes fall in a diameter range near the mean value, which allows us to evaluate the growth of the majority of inner tubes. Fig. 2b shows the area intensity of the peak composed of (12,3) and (13,1) tubes normalized to the intensity of the outer tube peak plotted against annealing temperature. The inner tubes grow rapidly with raising the temperature from 400 to 700 °C at and above which reactions to growth of inner tubes seem to be completed within 2 hours.

3.2. Chemical transformation of nickelocene

High-resolution TEM observations reveal nickel clusters formed inside SWCNTs by annealing, Fig. 3. From X-ray photoemission spectroscopy we gain further insights into the chemical transformation of nickelocene inside SWCNTs. Fig. 4a shows the Ni 2p spectra of the nickelocene-filled SWCNTs and those annealed at 250–1200 °C for 2 hours. The spectrum of the NiCp$_2$-filled SWCNTs exhibits two sharp peaks located at 854.53 eV and 871.80 eV binding energies, corresponding to the Ni 2p$_{3/2}$ and Ni 2p$_{1/2}$ edges, respectively. These peaks are not observed in the spectrum of the pristine SWCNTs. The energy positions are very similar to those reported previously for nickelocene absorbed on Ag(100). The Ni 2p spectra of the annealed samples show a successive downshift of the Ni 2p$_{3/2}$ and Ni 2p$_{1/2}$ peaks at increasing temperature. The Ni 2p$_{3/2}$ peak positions are summarized in Table 1. At the first three consecutive annealing steps at 250 °C, 300 °C and 340 °C, the Ni 2p$_{3/2}$ and Ni 2p$_{1/2}$ peaks are downshifted by 0.42 eV, 0.39 eV and 0.15 eV, respectively, and become much broader than the corresponding peaks of the NiCp$_2$-filled SWCNTs. Both features can be attributed to changes in the chemical state of nickel due to the formation of different nickel and carbon alloys (Ni$_x$C) following the decomposition of nickelocene. Upon annealing at temperatures above 400 °C they are further narrowed and downshifted and reach the energies for metallic nickel (Ni 2p$_{3/2}$ peak is at
transformed into metallic nickel. This suggests that nickel clusters act as catalysts for the growth of inner tubes, which ends when no more carbon atoms are available.

### 3.3. Charge transfer and bonding environment

Ultraviolet photoelectron spectroscopy provides further insights into the electronic structure of the filled SWCNTs and its response to the interior chemical transformation. Fig. 5 shows the valence band spectra of the pristine, nickelocene-filled SWCNTs and samples heated at 250–1200 °C for 2 hours. The spectra exhibit two characteristic peaks of nanotube’s sp² orbitals located at about 3 eV and 8 eV that correspond to the π- and σ-band, respectively.53,54 Because of the broad diameter distribution of pristine nanotubes, the one-dimensional van Hove singularities are not very pronounced. In the spectrum of NiCp₂-filled SWCNTs there is a broad peak located at binding energies from 0.6 to 1.9 eV. This peak is not observed for the pristine SWCNTs and vanishes after annealing, and hence can be assigned to the highest occupied molecular orbital of nickelocene. After the filling, the nanotube’s πpeak is shifted by 0.06 eV to a higher binding energy. An upshift of the π-peak was observed previously in the valence band spectra of SWCNTs intercalated with alkali metals55,56 and filled with ferrocene.25,32 Hence, this energy shift is confidently attributed to the electron transfer from the encapsulated nickelocene to the SWCNTs.

Furthermore, doping of the outer tubes can be traced by monitoring the π-peak energy shift at every annealing step, see Fig. 6a and Table 1. At 250 °C the π peak upshifts to a higher binding energy to reach a largest positive shift of 0.18 eV relative to the pristine SWCNT’s position. The energy shift becomes nearly zero at 600 °C, turns negative at higher temperatures, and reaches a maximum negative shift of −0.18 eV at ~853 eV.47,48

### Table 1

<table>
<thead>
<tr>
<th>Temperature °C</th>
<th>( N_{at}(Ni)/N_{at}(C) )</th>
<th>Ni content (%)</th>
<th>Ni 2p_{3/2} (eV)</th>
<th>( \pi ) (eV)</th>
</tr>
</thead>
<tbody>
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<td>SWCNT</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NiCp₂@SWCNT</td>
<td>0.0141</td>
<td>100</td>
<td>854.53</td>
<td>3.18</td>
</tr>
<tr>
<td>250</td>
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<td>853.11 (0.42)</td>
<td>3.36 (0.18)</td>
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<td>3.02 (0.16)</td>
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<td>3</td>
<td>853.04 (1.49)</td>
<td>3.00 (0.18)</td>
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</table>

The spectra exhibit two characteristic peaks of nanotube’s sp² orbitals located at about 3 eV and 8 eV that correspond to the π- and σ-band, respectively.53,54

From the area intensity ratio between the Ni 2p and C 1s edge photoelectron peaks, taking the photoemission cross sections into account, we calculate the number of nickel atoms relative to carbon atoms. For the NiCp₂-filled sample this value \( N_{at}(Ni)/N_{at}(C) \) equals 0.0141. This is about 4.5 times as large as 0.0031 reported for ferrocene-filled SWCNTs,25,32 which testifies to a high filling degree of SWCNTs with nickelocene, and is in agreement with the Raman spectroscopy data discussed in the previous section. The calculated nickel-to-carbon atomic ratios \( N_{at}(Ni)/N_{at}(C) \) as well as Ni contents defined as the atomic ratios normalized by the value of NiCp₂-filled SWCNTs are plotted in Fig. 4b and summarized in Table 1.

Upon annealing at temperatures below 400 °C the Ni content is reduced only to 90% or higher. At 450–600 °C it goes down to 69%. The loss becomes substantial at higher temperatures. The quantity of nickel is reduced to 33% at 800 °C, equals 13% at 1000 °C, and then at 1200 °C almost all nickel atoms are removed from the sample (Fig. 4b). The loss of nickel atoms is in line with observations on the annealed ferrocene-filled SWCNTs.25 However, for ferrocene no metallic nanoparticles could be achieved; only stable iron carbide is formed. In the present case, nickel carbides are initially formed at temperatures in the range of 250–400 °C and then transformed entirely into metallic nickel at 600 °C. As seen in Fig. 2b, the majority of inner tubes are formed within the temperature range of 450–650 °C where nickel carbides are transformed into metallic nickel. This suggests that nickel
1200 °C. The π peak shifts to lower binding energies, which were reported recently for carbon nanotubes filled with copper57 and zinc halogenides,58 can be attributed to hole doping of the SWCNTs. All photoemission data support that the charge transfer can be tuned via the chemical transformation that allows both electron and hole doping of SWCNTs to be achieved at different levels.

Doping of nanotubes is controlled by several processes that are dependent on annealing temperature: (i) chemical transformation of nickelocene, (ii) growth of inner tubes, and (iii) evaporation of nickel. Nickelocene, nickel carbides and metallic nickel have an electron doping effect on the SWCNTs. It leads to the upshift of the Fermi level with respect to the SWCNTs' density of states (Fig. 6b and c). In turn, we observed that the growth of inner tubes starts at 400 °C. This means that the SWCNTs annealed at temperatures higher than 400 °C contain carbon inner tubes as well as nickel compounds. The latter evaporates at high temperatures, which leaves pure DWCNTs after annealing at 1200 °C. In DWCNTs there is electron transfer from the outer tube to the inner tube (Fig. 6d).

For a quantitative analysis, we calculate the total number of transferred electrons per outer tube carbon atom $N_{\text{total}}$ (e$^{-}$/carbon) and the charge transfer density per nanotube length CT (e$^{-}$/Å) by comparing the Fermi level shifts with those for potassium-doped SWCNTs55 (Fig. 6a and Table 2). $N_{\text{total}} = 0.00046$ e$^{-}$/carbon is obtained for the nickelocene-filled SWCNTs. Provided that the 1.7 nm diameter SWCNT has 20.32 carbon atoms per 1 Å of length, this corresponds to CT = 0.00933 e$^{-}$/Å. At 250 °C the values jump to maxima of 0.00118 e$^{-}$/carbon and 0.02399 e$^{-}$/Å, then drop steeply, become negative with increasing temperature, and hit negative maxima of -0.00118 e$^{-}$/carbon and -0.02399 e$^{-}$/Å at 1200 °C. These values are larger than 0.00042 e$^{-}$/carbon and 0.00672 e$^{-}$/Å reported for ferrocene-filled SWCNTs and much larger than -0.00029 e$^{-}$/carbon and -0.00472 e$^{-}$/Å for the ferrocene-made DWCNTs.25,32 Note that for a given electron number per carbon, the doping level per angstrom calculated here is proportional to the nanotube’s mean diameter which is 1.7 nm in the present study and 1.4 nm in the previous work.

The greater doping with nickelocene than ferrocene could be due to the higher filling degree of SWCNTs obtained in the present study; a nickel to carbon ratio of $N_{\text{Ni}}$/N$\text{C} = 0.0141$ is 4.5 times as high as an iron to carbon ratio of 0.0031 for the ferrocene-filled SWCNTs.25,32 This explains well the DWCNT’s hole doping level of -0.00118 e$^{-}$/carbon in the present case, 4.1 times as high as -0.00029 e$^{-}$/carbon in the previous work since the yield of inner tubes to grow is proportional to the initial filling degree. But the electron doping level per carbon obtained with nickelocene is larger by only 10% as compared to the ferrocene case. If the doping level

### Table 2: Total number of electrons transferred to the nanotube’s carbon atom $N_{\text{total}}$ (e$^{-}$/carbon) and the charge transfer density (CT) of the outer tube along the tube axis in units of e$^{-}$/Å.

<table>
<thead>
<tr>
<th>Temperature (°C)</th>
<th>$N_{\text{total}}$ (e$^{-}$/carbon)</th>
<th>CT (e$^{-}$/Å)</th>
<th>$N_{\text{filler}}$ (e$^{-}$/carbon)</th>
<th>$N_{\text{filler}}$ (e$^{-}$/Ni)</th>
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<tbody>
<tr>
<td>SWCNT</td>
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<tr>
<td>NiCp$_2$@SWCNT</td>
<td>0.00046</td>
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<td>0.00046</td>
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transferred electrons per nickel atom diameter.  

depends on the type of metal and possibly the nanotube valuation poses the question of how the doping efficiency is smaller for larger diameter inner tubes as well.  

In order to clarify this point we calculate the number of transferred electrons per nickel atom \( N_{\text{eff}} \). As discussed before, the evolution of the doping level is controlled by three consecutive (partly overlapping) processes: chemical transformation of nickelocene, growth of inner tubes and evaporation of nickel. The encapsulated dopants that contribute to the doping level per carbon in unison are nickelocene, nickel carbides, metallic nickel and inner tubes. First, we disentangle the intra-tube charge transfer between the inner and outer tubes from the rest which contains nickel substances. Fig. 7a shows the number of transferred electrons per carbon atom (red) and the area intensity of the RBM peak for mean-diameter inner tubes (black) plotted against annealing temperature. Taking into account that annealing at 1200 °C forms empty DWCNTs, we normalize the RBM area intensity data to the maximum doping level at 1200 °C and then subtract them from the doping level data. The difference curve \( N_{\text{eff}} \) (e\(^{-}\) per carbon) in blue represents the partial doping per outer tube carbon caused by the encapsulated nickel substances apart from the inner carbon tubes. It stays positive, which means that all nickel substances are electron donors. This is rational since they are nickel carbidies and/or nickel.

In contrast to the total doping level (red), which exhibits a monotonic change from positive to negative with increasing temperature, the curve in blue has a local minimum of 0.00059 e\(^{-}\) per carbon at 450 °C followed by a maximum of 0.00123 e\(^{-}\) per carbon at 600 °C. The latter coincides with the completion of nickel carbide to metallic nickel transformation, suggesting the effect of chemical transformation. Divided by the nickel-to-carbon ratio \( N_{\text{eff}}(\text{Ni})/N_{\text{eff}}(\text{C}) \) (Fig. 7b), the curve represents the partial doping level per nickel atom \( N_{\text{filler}} \) (e\(^{-}\) per Ni), plotted in Fig. 7c and summarized in Table 2. Now it shows that the doping efficiency per nickel varies as the chemical status changes. The doping level begins at 0.0327 e\(^{-}\) per Ni after filling with nickelocene, jumps to a moderately high value of 0.0864 e\(^{-}\) per Ni at 250 °C, drops to reach a minimum level of 0.0541 e\(^{-}\) per Ni at 400 °C, increases to reach 0.1268 e\(^{-}\) per Ni at 600 °C and stays constant at higher temperatures. From a comparison to the interior chemical state at each annealing step assigned by the XPS measurements, we can judge that the initial jump is caused by the decomposition of nickelocene to various nickel carbides Ni\(x\)C, which are stable below 400 °C. As the temperature approaches 400 °C, carbides transform into a more stable Ni\(x\)C for which doping efficiency is the lowest. Within a temperature range of 450–600 °C, Ni\(x\)C transforms into metallic nickel which has the highest doping efficiency. Metallic nickel does not undergo further chemical transformations, which explains the constant doping efficiency at higher temperatures.

Note that the doping level for the nickelocene-filled SWCNTs equals 0.0327 e\(^{-}\) per Ni (dashed horizontal line in Fig. 7c). This is substantially smaller than 0.14 e\(^{-}\) per Fe reported for ferrocene in SWCNTs. The charge transfer between SWCNTs and organic molecules should depend on the ionization energy or the electron affinity of guest molecules. The reported ionization energy of ferrocene is 6.86 eV (or 6.72 eV), which is larger than the 6.50 eV (or 6.2 eV) of nickelocene. It means that as opposed to the experimental result, nickelocene encapsulated in SWCNTs should have a larger doping efficiency. In turn, it was reported that the charge-transfer interaction between SWCNTs and molecules is strongly dependent on the reduction potential of nanotubes as well. The work function of SWCNTs was found to scale inversely with nanotube diameter. Larger diameter SWCNTs have smaller work function, which can be understood that the electron doping efficiency is smaller for larger diameter SWCNTs as electron acceptors. Although this scenario can be adapted to explain the difference in doping efficiency between nickelocene and ferrocene encapsulated in the 1.4 and 1.7 nm diameter SWCNTs respectively, it is insufficient for the asymmetric electron and hole doping observed in the nickelocene case to be explained.

Another scenario would be that a high filling degree of SWCNTs achieved for larger diameter SWCNTs could result in...
a reduced doping efficiency. In contrast to the case of 1.4 nm diameter SWCNTs that can accommodate no more than one ferrocene molecule in SWCNT's circular cross section, very large atomic concentration of nickel \(N_{\text{Ni}}(\text{Ni})/N_{\text{at}(\text{C})} = 0.0141\) is interpreted that on average 2.87 molecules should fill the SWCNT's circular cross section in which molecules are not only in contact with nanotubes, but also interact with one another. Some can be not in direct contact with nanotubes, which leads to the charge distribution to be rearranged in such a way that the doping level of the SWCNT is reduced.

4. Conclusions

In conclusion, we have shown that SWCNTs can be filled with nickelocene, which was reacted to form nickel carbides, nickel and inner carbon nanotubes as identified by XPS, TEM and Raman spectroscopy. Charge transfer interaction within the SWCNTs has been accessed by UPS, that elucidated both electron and hole doping of the SWCNTs controlled in a broad range of \(\pm 0.0012\) e\(^{-}\) per carbon at reaction temperatures as low as 250 °C. This makes our endohedral process compatible with microscopic barrier to be tuned in a controlled manner at microscopic range of ±0.0012 e\(^{-}\). In contrast to the case of 1.4 nm SWCNTs, in which molecules are not only in contact with nanotubes, but also interact with one another. Some can be not in direct contact with nanotubes, which leads to the charge distribution to be rearranged in such a way that the doping level of the SWCNT is reduced.

Acknowledgements

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Notes and references


According to the previous work, the work function of the 1.7 nm SWCNT is about 4.1 eV, smaller by 0.6 eV than 4.7 eV of the 1.4 nm SWCNT. For the same molecule the degree of electron charge transfer can be smaller by $\Delta N = 0.6 \times \text{DOS} \ [e^- \text{per carbon per eV}]$, where DOS is the cumulative density of states in the vicinity of the Fermi level. From the tight binding calculation for the 1.7 ± 0.1 nm diameter SWCNTs, we obtain DOS = $3.18 \times 10^{-3}$, hence $\Delta N = 0.0019 e^-$ per carbon. From the nickel to carbon ratio $N_{\text{at(Ni)}}/N_{\text{at(C)}} = 0.0141$, it corresponds to $\Delta N = 0.135 e^-$ per nickel, which can reasonably narrow the gap between the two different cases.